Silicon Zener Diode







Features

- · Planar die construction
- · 350mW power dissipation
- Zener voltages from 3.3V
- · Ideally suited for automated assembly processes
- · Epoxy meets UL 94 V-0 flammability rating
- · Moisture sensitivity level 1
- Weight: 0.008 grams (approx.)

Max. Ratings and Electrical Characteristics

Single phase, half wave, 60Hz, resistive or inductive load. For capacitive load, derate current by 20%

Parameter	Symbol	Rating	Units
Maximum Forward Voltage @ IF = 10mA	VF	0.9	V
Power Dissipation (Note A)	P(AV)	350	mW
Operation and Storage Temperature	TJ, Tsтg	-55 to +150	°C
Peak Forward Surge Current (Note B)	IFSM	2	А
Thermal Resistance (Note C)	RthJA	357	°C/W

- Notes: A. Mounted on 5mm² (0.013mm thick) land areas.
 - B. Measured on 8.3ms, single half sine-wave or equivalent square wave, duty cycle = 4 pulses per minute maximum.
 - C. Valid provided the terminals are kept at ambient temperature.

Electrical Characteristics (TA = 25°C unless otherwise noted)

	No	minal Ze	_	Max. Zener Impedance			Max. Reverse Leakage Current			
Part Number	٧	/z(V) @ I z	т.	Z zt @	lzт	Z zk @	Izĸ	Ir @	V R	Marking
	Nom.	Min.	Max.	Ω	mA	Ω	mA	μA	V	
BZX84C3V3+	3.3	3.1	3.5	95	5	600	1	5	1	W4/Z14

Notes:

- 1. Standard zener voltage tolerance is ±5% with a 'C' suffix.
- 2. Zener Voltage (Vz) Measurement. Guarantees the zener voltage when measured at 90 seconds while maintaining the lead temperature (TL) AT 30°C from the diode body.
- 3. Zener Impedance (Zz) Derivation. The zener impedance os dervied from the 60 cycle ac voltage, which results when an AC current having an rms value equal to 10% of the DC zener current (Izt or Izk) is superimposed on IzT or Izk.
- 4. Surge Current (IR) Non-Repetitive. The rating listed in the electrical characteristics table is maximum peak, non-repetitive, reverse surge current of 1/2 square wave or equivalent sine wave pulse of 1/120 second duration superimposed on the test current, I_{ZT}, per JEDEC registration.

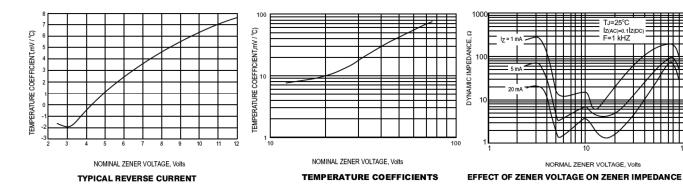
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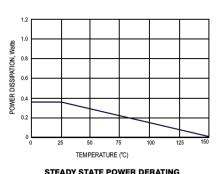


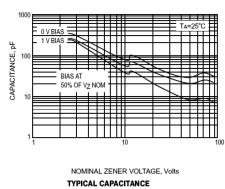
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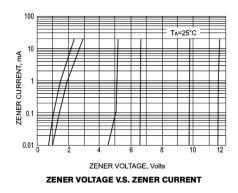


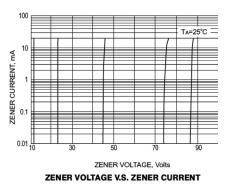
Rating and Characteristic Curves

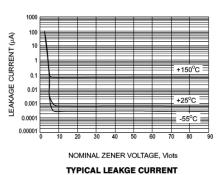












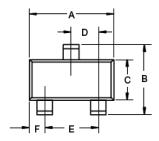
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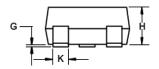


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Dimension:







SOT-23				
Dim.	Min.	Max.		
Α	2.8	3.04		
В	2.1	2.64		
С	1.2	1.4		
D	0.89	1.03		
Е	1.78	2.05		
F	0.45	0.6		
G	0.013	0.1		
Н	0.89	1.12		
J	0.085	0.18		
K	0.37	0.51		
L	0.2	0.5		

Dimensions: Millimetres

Part Number Table

Description	Part Number	
Zener - Single 350mW 3.3V SOT-23	BZX84C3V3+	

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